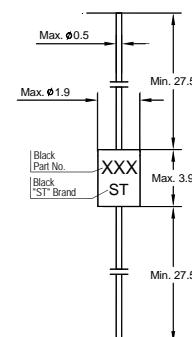


## Silicon Bidirectional Trigger Diodes

These diacs are intended for use in thyristor phase control, circuits for lamp-dimming, universal-motor speed controls, and heat controls.



Glass Case DO-35  
Dimensions in mm

Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Power Dissipation ( $T_a = 65^\circ\text{C}$ )	$P_{\text{tot}}$	150	mW
Repetitive Peak On-state Current ( $t_p = 20 \mu\text{s}$ , $f = 100 \text{ Hz}$ )	$I_{\text{TRM}}$	2	A
Operating Junction and Storage Temperature Range	$T_j, T_{\text{stg}}$	- 40 to + 125	°C

Characteristics at  $T_a = 25^\circ\text{C}$ 

Parameter	Symbol	Min.	Max.	Unit
Breakover Voltage at $C = 22 \text{ nF}$ , see diagram 1	$V_{\text{BO}}$	28	36	V
		30	38	
		35	45	
Breakover Voltage Symmetry at $C = 22 \text{ nF}$ , see diagram 1	$[+V_{\text{BO}} - V_{\text{BO}}]$	-	3	V
Dynamic Breakover Voltage at $\Delta I = [I_{\text{BO}} \text{ to } I_F = 10 \text{ mA}]$	$ \Delta V \pm $	5	-	V
Output Voltage See diagram 2	$V_O$	5	-	V
Breakover Current at $C = 22 \text{ nF}$	$I_{\text{BO}}$	-	50	µA
Leakage Current at $V_B = 0.5 V_{\text{BO}} \text{ max}$	$I_B$	-	10	µA
Rise Time See diagram 3	$t_r$	-	2	µs

Diagram 1: Current-voltage characteristics

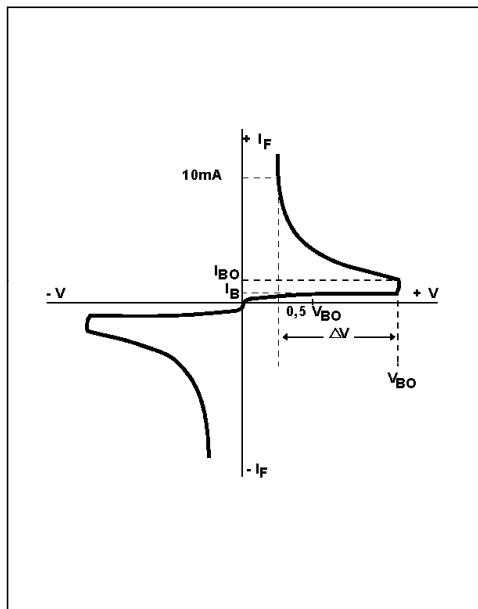


Diagram 2: Test circuit for output voltage

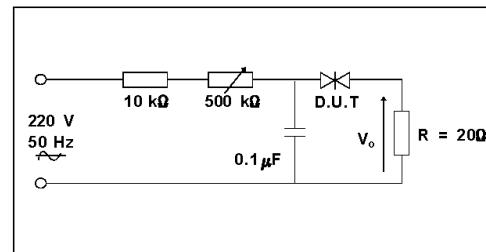


Diagram 3: Test circuit see diagram 2.  
Adjust R for  $I_p=0.5A$

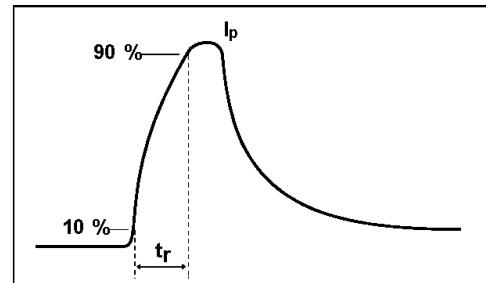


Fig. 1: Power dissipation versus ambient temperature (maximum values)

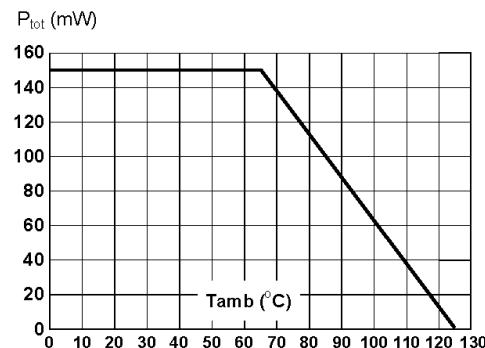


Fig. 2: Relative variation of  $V_{BO}$  versus junction temperature (typical values)

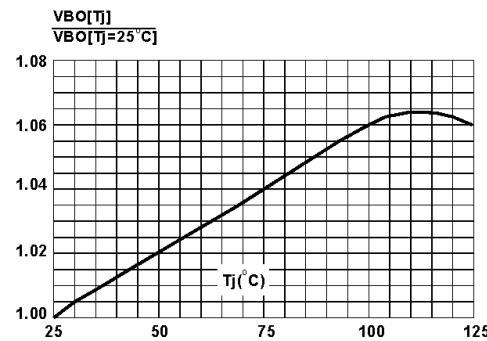


Fig. 3: Peak pulse current versus pulse duration (maximum values)

